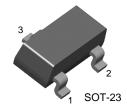


BCX70G

General Purpose Transistor



1. Base 2. Emitter 3. Collector

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	45	V
V _{CEO}	Collector-Emitter Voltage	45	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current	200	mA
P _C	Collector Power Dissipation	350	mW
T _{STG}	Storage Temperature	-55 ~ 150	°C

Refer to KST5088 for graphs

$\textbf{Electrical Characteristics} \ \, \textbf{T}_{a} \!\!=\!\! 25^{\circ} \textbf{C} \ \, \textbf{unless otherwise noted}$

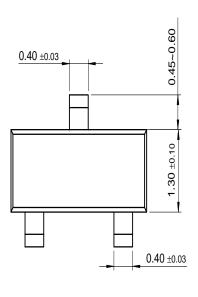
Symbol	Parameter	Test Condition	Min.	Max.	Units
BV_{CEO}	Collector-Emitter Breakdown Voltage	$I_C=2mA$, $I_B=0$	45		V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E =1μA, I _C =0	5		V
I _{CES}	Collector Cut-off Current	V_{CE} =32V, V_{BE} =0		20	nA
I _{EBO}	Emitter Cut-off Current	$V_{EB}=4V$, $I_{C}=0$		20	nA
h _{FE}	DC Current Gain	V_{CE} =5V, I_{C} =2mA V_{CE} =1V, I_{C} =50mA	120 60	220	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =10mA, I _B =0.25mA I _C =50mA, I _B =1.25mA		0.35 0.55	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C =10mA, I _B =0.25mA I _C =50mA, I _B =1.25mA	0.6 0.7	0.85 1.05	V
V _{BE} (on)	Base-Emitter On Voltage	I _C =2mA, V _{CE} =5V	0.55	0.75	V
f _T	Current Gain Bandwidth Product	V _{CE} =5V, I _C =10mA	125		MHz
C _{ob}	Output Capacitance	V _{CB} =10V, I _E =0, f=1MHz		4.5	pF
NF	Noise Figure	I_{C} =0.2mA, V_{CE} =5V f=1KHz, R_{S} =2K Ω		6	dB
t _{ON}	Turn On Time	I _C =10mA, I _{B1} =1mA		150	
t _{OFF}	Turn Off Time	I_{B2} =1mA, V_{BB} =3.6V R_L =990Ω R_1 = R_2 =5KΩ		800	ns ns

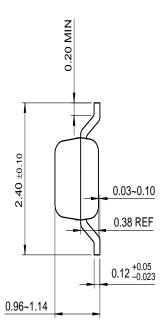


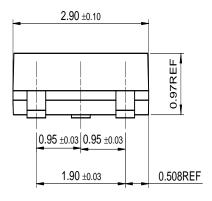


Package Dimensions

SOT-23







Dimensions in Millimeters

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E ² CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	I^2C^{TM}	OCX^{TM}	RapidConfigure™	UHC™
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Programmable Active Droop™		OPTOPLANAR™	SMART START™	

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